

LM1877 Dual Audio Power Amplifier

General Description

The LM1877 is a monolithic dual power amplifier designed to deliver 2W/channel continuous into 8Ω loads. The LM1877 is designed to operate with a low number of external components, and still provide flexibility for use in stereo phonographs, tape recorders and AM-FM stereo receivers, etc. Each power amplifier is biased from a common internal regulator to provide high power supply rejection, and output Q point centering. The LM1877 is internally compensated for all gains greater than 10.

Features

- 2W/channel
- -65 dB ripple rejection, output referred
- -65 dB channel separation, output referred

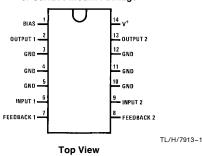
- Wide supply range, 6V-24V
- Very low cross-over distortion
- Low audio band noise
- AC short circuit protected
- Internal thermal shutdown

Applications

- Multi-channel audio systems
- Stereo phonographs
- Tape recorders and players
- AM-FM radio receivers
- Servo amplifiers
- Intercom systems
- Automotive products

Connection Diagram

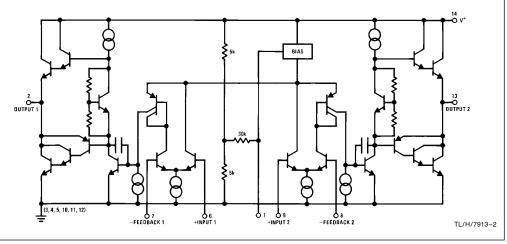
Dual-In-Line Package or Surface Mount Package



See NS Package Number M14B or N14A

Order Number LM1877M-9 or LM1877N-9

Equivalent Schematic Diagram



Absolute Maximum Ratings
If Military/Aerospace specified devices are required, Lead Temperature please contact the National Semiconductor Sales Office/Distributors for availability and specifications. N-Package Soldering (10 sec.) M-Package Infared (15 sec.) M-Package Vapor Phase (60 sec.)

Supply Voltage $\pm\,0.7V$ Thermal Resistance

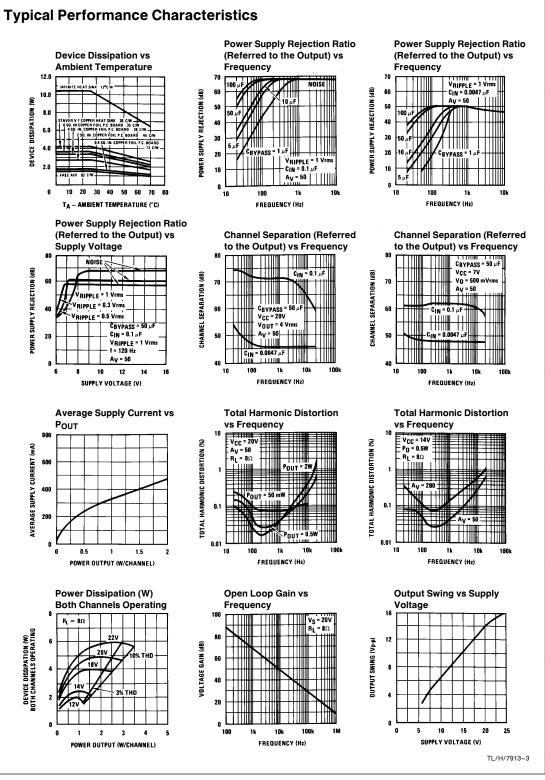
Input Voltage 30°C/W θ_{JC} (N-Package) 0°C to +70°C Operating Temperature θ_{JA} (N-Package) 79°C/W Storage Temperature -65°C to $+150^{\circ}\text{C}$ θ_{JC} (M-Package) θ_{JA} (M-Package) 27°C/W Junction Temperature 150°C 114°C/W

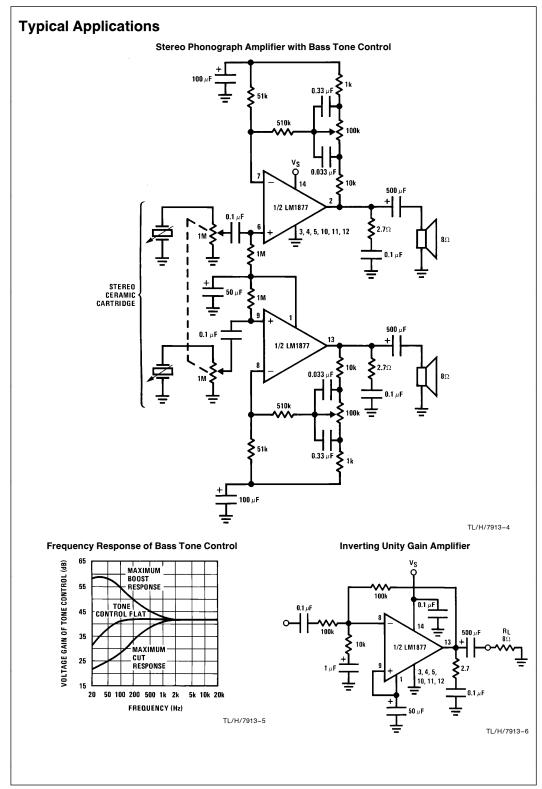
260°C 220°C 215°C

Electrical Characteristics V_S = 20V, T_A = 25°C, (See Note 1) R_L = 8Ω , A_V = 50 (34 dB) unless otherwise specified

Parameter	Conditions	Min	Тур	Max	Units
Total Supply Current	$P_O = 0W$		25	50	mA
Output Power LM1877	$THD = 10\%$ $V_S = 20V, R_L = 8\Omega$ $V_S = 12V, R_L = 8\Omega$	2.0	1.3		W/Ch W/Ch
Total Harmonic Distortion LM1877	$f = 1 \text{ kHz}, V_S = 14V$				
	P _O = 50 mW/Channel		0.075		%
	P _O = 500 mW/Channel		0.045		%
	P _O = 1 W/Channel		0.055		%
Output Swing	$R_L = 8\Omega$		V _S -6		Vp-p
Channel Separation	$C_F = 50 \ \mu F, C_{IN} = 0.1 \ \mu F,$ $f = 1 \ kHz, Output \ Referred$				
	$V_S = 20V, V_O = 4 \text{ Vrms}$	-50	-70		dB
	$V_{S} = 7V, V_{O} = 0.5 \text{ Vrms}$		-60		dB
PSRR Power Supply Rejection Ratio	$C_F = 50 \ \mu F, C_{IN} = 0.1 \ \mu F,$ f = 120 Hz, Output Referred				
	$V_S = 20V, V_{RIPPLE} = 1 Vrms$	-50	-65		dB
	$V_S = 7V$, $V_{RIPPLE} = 0.5 Vrms$		-40		dB
Noise	Equivalent Input Noise				
	$\label{eq:RS} \begin{split} R_S = 0, C_{IN} = 0.1 \; \mu\text{F}, \\ BW = 20 \; \text{Hz-}20 \; \text{kHz}, \text{Output Noise Wideband} \end{split}$		2.5		μV
	$R_S = 0, C_N = 0.1 \mu F, A_V 200$		0.80		mV
Open Loop Gain	$R_{S}=0$, f = 100 kHz, $R_{L}=8\Omega$		70		dB
Input Offset Voltage			15		mV
Input Bias Current			50		nA
Input Impedance	Open Loop		4		MΩ
DC Output Level	V _S = 20V	9	10	11	V
Slew Rate			2.0		V/μs
Power Bandwidth			65		kHz
Current Limit			1.0		Α

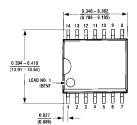
Note 1: For operation at ambient temperature greater than 25°C, the LM1877 must be derated based on a maximum 150°C junction temperature.

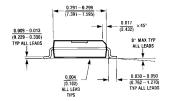


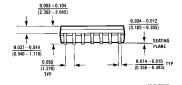


Typical Applications (Continued) Stereo Amplifier with $A_V=\,200$ 1/2 LM1877 TL/H/7913-7 Non-Inverting Amplifier Using Split Supply **Typical Split Supply** 1/2 LM1877 TL/H/7913-9 TL/H/7913-8

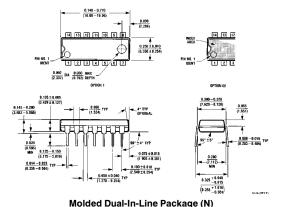
Physical Dimensions inches (millimeters)







Molded SOIC Package (M) Order Number LM1877M-9 NS Package Number M14B



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Order Number LM1877N-9 NS Package Number N14A

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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